



#### 30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

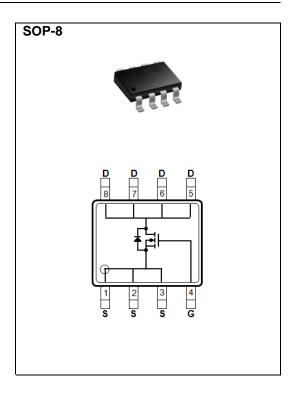
16 A

#### **Features**

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@10V, I<sub>D</sub>@10A<4.2mΩ
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@5A<6m\Omega$
- · High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMET	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V <sub>DS</sub>	30	- v	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current	T <sub>A</sub> =25°C		16		
	T <sub>A</sub> =70°C	I <sub>D</sub>	13	Α	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	64		
Power Dissipation	T <sub>A</sub> =25°C		2.1	W	
	T <sub>A</sub> =70°C	P <sub>D</sub>	1.3		
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 5)		$R_{ heta JA}$	59.5	°C/W	





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			_			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1	1.6	2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =10A -	3.5	4.2		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A	-	5.2	6	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)			_			
Total Gate Charge	$Q_g$	V <sub>DS</sub> =15V, I <sub>D</sub> =24A, V <sub>GS</sub> =4.5V <sup>(Note 2,3)</sup>	-	23	-	nC
Gate-Source Charge	$Q_gs$		-	8	-	
Gate-Drain Charge	$Q_{gd}$		-	9	-	
Input Capacitance	Ciss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0MHZ	-	2436	-	pF
Output Capacitance	Coss		-	306	-	
Reverse Transfer Capacitance	Crss		-	196	-	
Turn-On Delay Time	td <sub>(on)</sub>	\/ 45\/   45\	-	32	-	ns
Turn-On Rise Time	tr	$V_{DS}$ =15V, $I_{D}$ =15A, $V_{GS}$ =10V, $R_{G}$ =1 $\Omega$ (Note 2,3)	-	169	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	232	-	
Turn-Off Fall Time	tf		-	170	-	
Drain-Source Diode		<del>,</del>				
Maximum Continuous Drain-Source			-	-	16	А
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.66	1	V

#### NOTES:

- 1. Pulse width<a>300us</a>, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

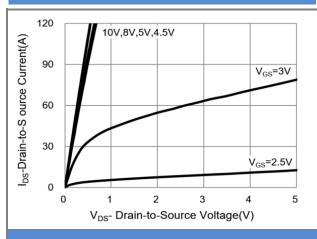
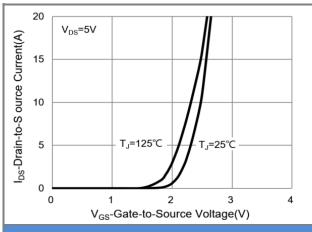


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

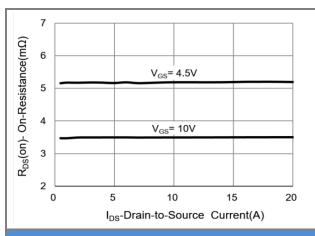


Fig.3 On-Resistance vs. Drain Current

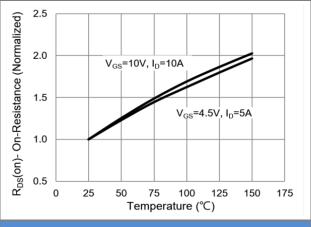
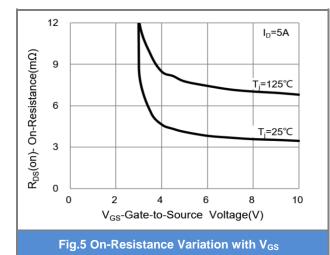
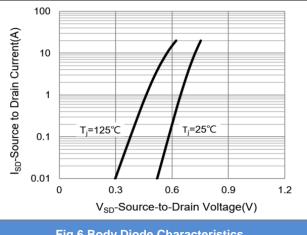


Fig.4 On-Resistance vs. Junction temperature





**Fig.6 Body Diode Characteristics** 





#### **TYPICAL CHARACTERISTIC CURVES**

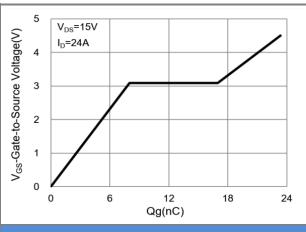


Fig.7 Gate-Charge Characteristics

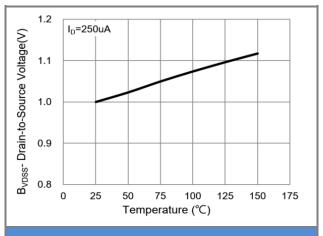


Fig.8 Breakdown Voltage Variation vs. Temperature

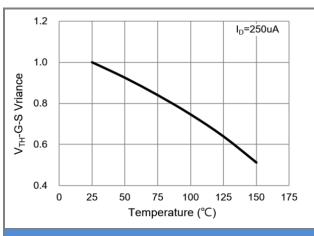


Fig.9 Threshold Voltage Variation with Temperature

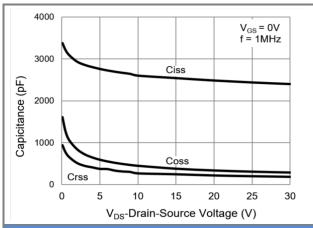


Fig.10 Capacitance vs. Drain-Source Voltage

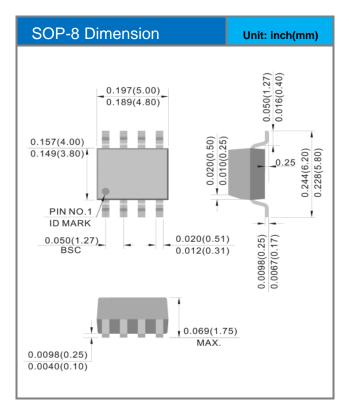


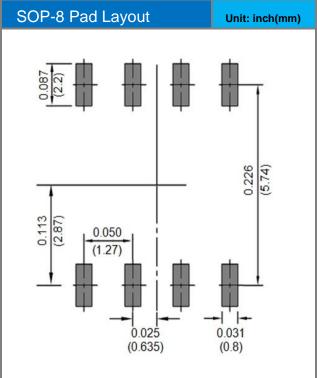


### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJL9416_R2_00001	SOP-8	2.5K pcs / 13" reel	L9416	Halogen free

### **Packaging Information & Mounting Pad Layout**









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